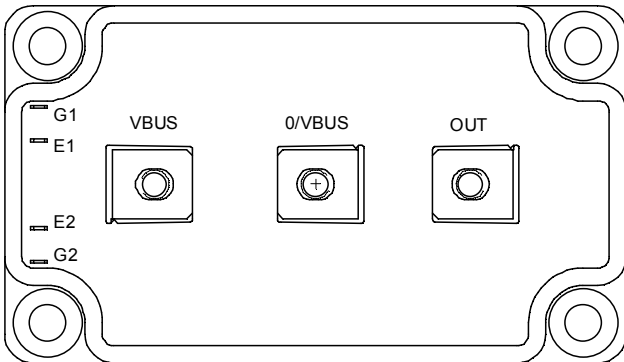
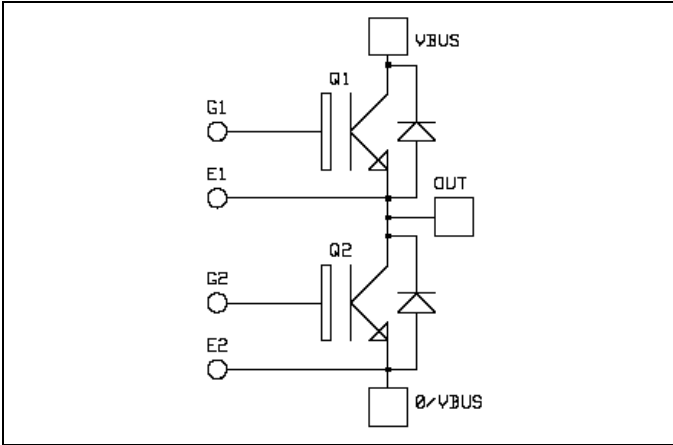


*Phase leg
NPT IGBT Power Module*

**$V_{CES} = 600V$
 $I_C = 350A @ T_c = 80^\circ C$**



Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) THUNDERBOLT IGBT®
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - Avalanche energy rated
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCESat

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage	600	V
I_C	Continuous Collector Current	$T_c = 25^\circ C$	430
		$T_c = 80^\circ C$	350
I_{CM}	Pulsed Collector Current	$T_c = 25^\circ C$	1225
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$	1562
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^\circ C$	1225A @ 600V

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
BV_{CES}	Collector - Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 200\mu A$	600			V
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V$			200	μA
		$V_{CE} = 600V$			4000	
$V_{CE(on)}$	Collector Emitter on Voltage	$V_{GE} = 15V$		2.0	2.5	V
		$I_C = 360A$		2.2		
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 4mA$	3		5	V
I_{GES}	Gate - Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$			± 300	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
C_{ies}	Input Capacitance	$V_{GE} = 0V$		17.2		nF	
C_{oes}	Output Capacitance	$V_{CE} = 25V$		1.88			
C_{res}	Reverse Transfer Capacitance	$f = 1MHz$		1.6			
Q_g	Total gate Charge	$V_{GS} = 15V$		1320		nC	
Q_{ge}	Gate - Emitter Charge	$V_{Bus} = 300V$		1160			
Q_{gc}	Gate - Collector Charge	$I_C = 360A$		800			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 360A$ $R_G = 1.25\Omega$		26		ns	
T_r	Rise Time			25			
$T_{d(off)}$	Turn-off Delay Time			150			
T_f	Fall Time			30			
E_{on}	Turn-on Switching Energy ❶			13.5			mJ
E_{off}	Turn-off Switching Energy ❷			11.5			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 360A$ $R_G = 1.25\Omega$		26		ns	
T_r	Rise Time			25			
$T_{d(off)}$	Turn-off Delay Time			170			
T_f	Fall Time			40			
E_{on}	Turn-on Switching Energy ❶			17.2			mJ
E_{off}	Turn-off Switching Energy ❷			14			

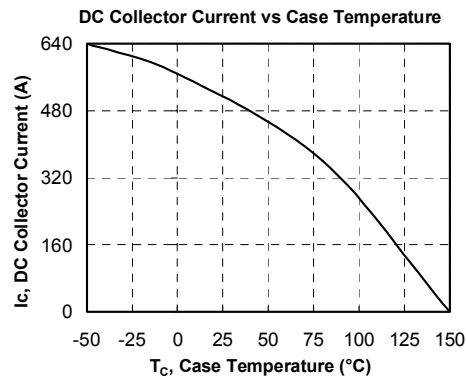
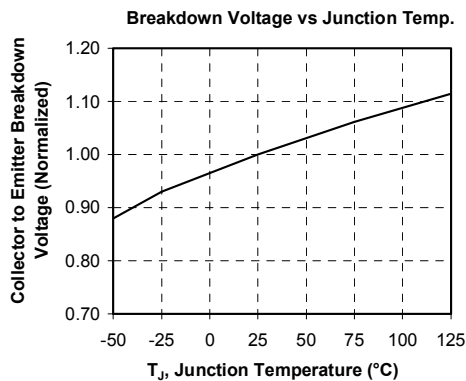
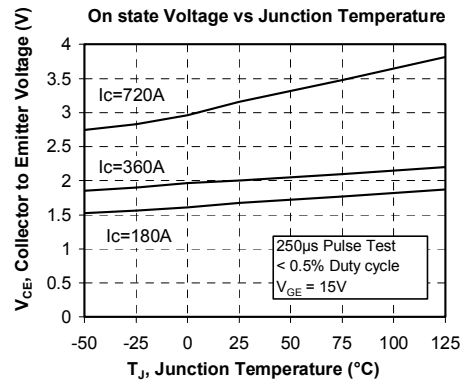
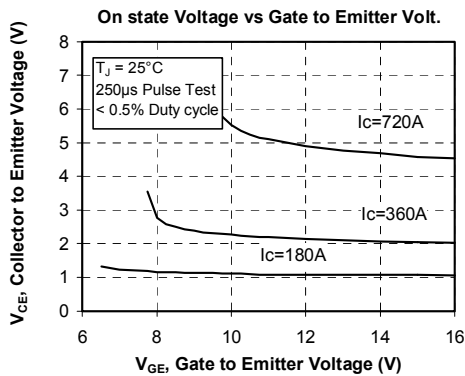
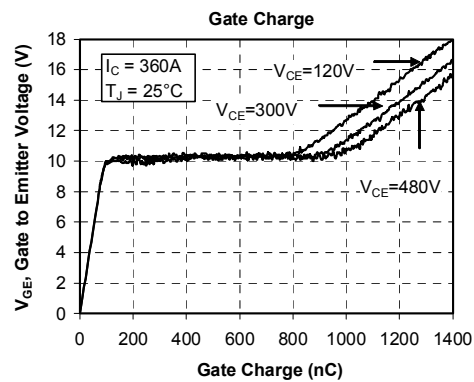
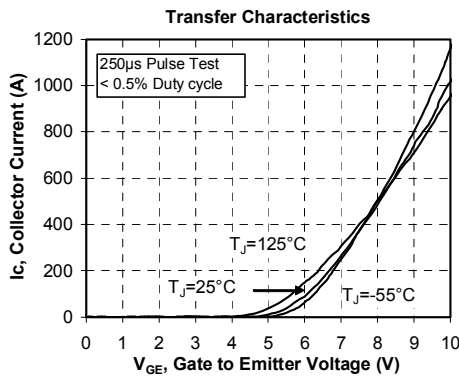
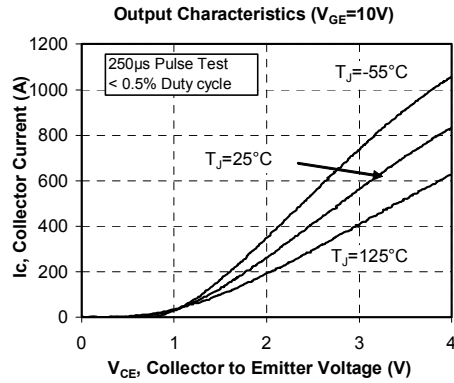
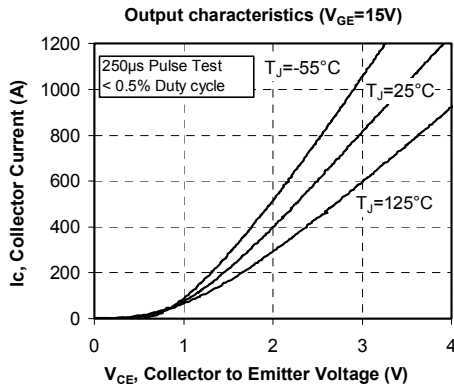
Reverse diode ratings and characteristics

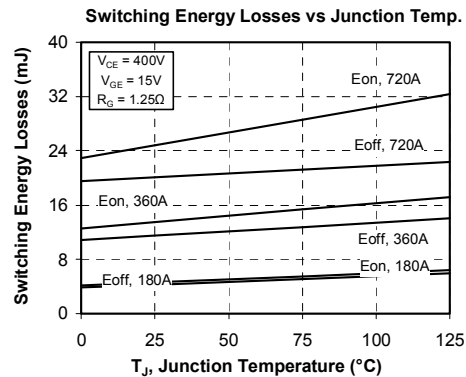
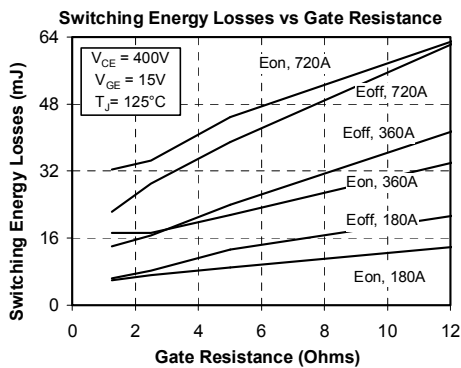
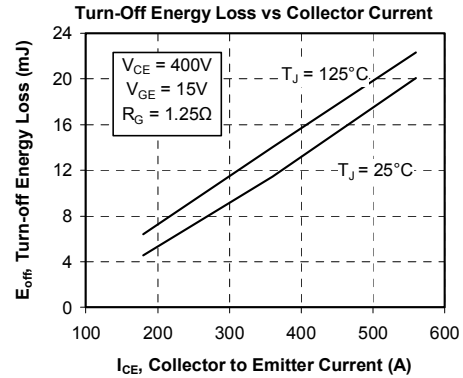
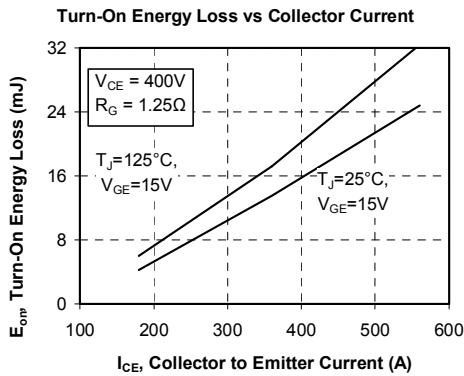
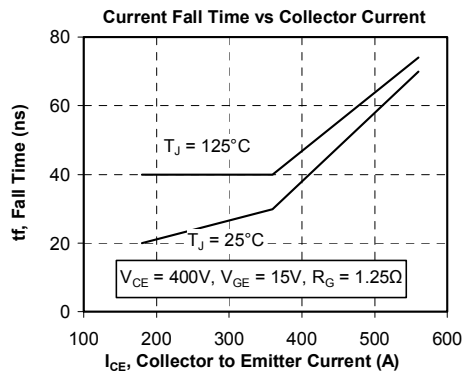
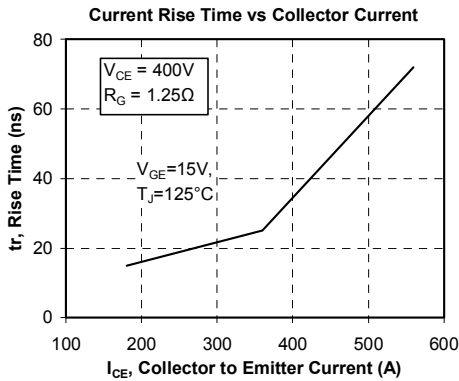
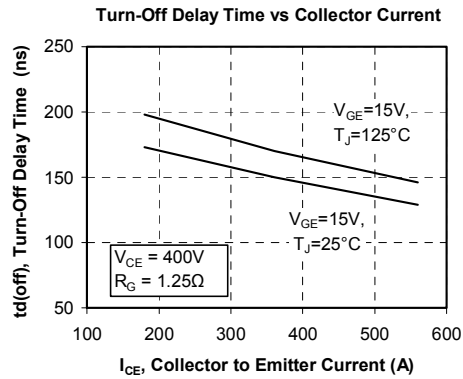
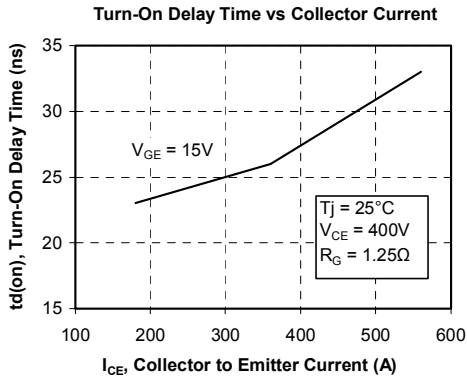
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{F(AV)}$	Maximum Average Forward Current	50% duty cycle $T_c = 80^\circ\text{C}$		400		A
V_F	Diode Forward Voltage	$I_F = 400A$		1.6	1.8	V
		$I_F = 800A$		1.9		
		$I_F = 400A$	$T_j = 125^\circ\text{C}$	1.4		
t_{rr}	Reverse Recovery Time	$I_F = 400A$	$T_j = 25^\circ\text{C}$	180		ns
		$V_R = 400V$ $di/dt = 800A/\mu s$	$T_j = 125^\circ\text{C}$	220		
Q_{rr}	Reverse Recovery Charge	$I_F = 400A$	$T_j = 25^\circ\text{C}$	1560		nC
		$V_R = 400V$ $di/dt = 800A/\mu s$	$T_j = 125^\circ\text{C}$	5800		

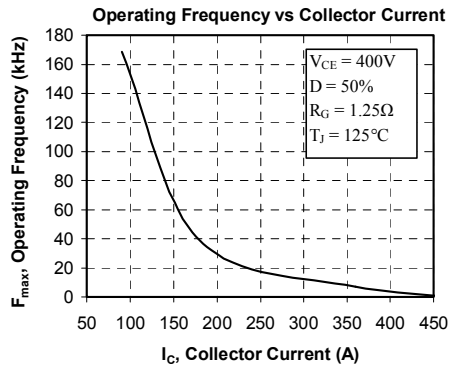
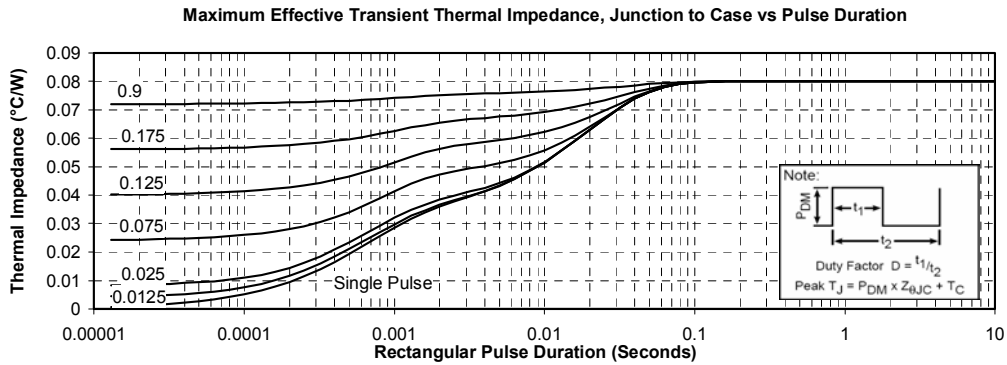
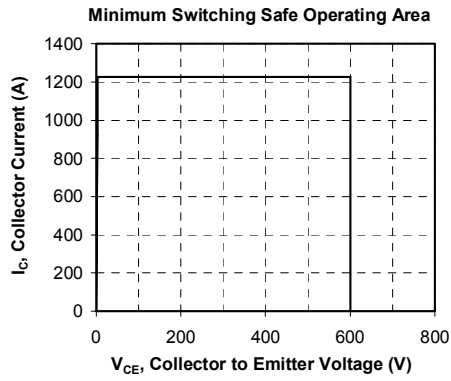
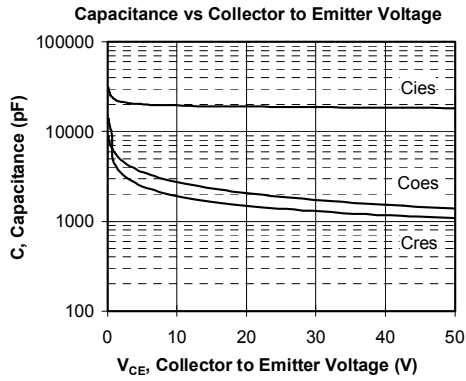
❶ E_{on} includes diode reverse recovery

❷ In accordance with JEDEC standard JESD24-1

Typical Performance Curve







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APT's products are covered by one or more of U.S. patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.

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